

Amendments to the Specification:

Please amend the specification as follows:

Page 8, please insert the following paragraph between lines 11 and 12:

Figure 1F-3 a simplified, partial, exploded, cross-sectional view of the post-etched low-K dielectric filled semiconductor structure of Figure 1F including the supporting stubs, as covered with a passivation-capping layer, in accordance with still another embodiment of the present invention.